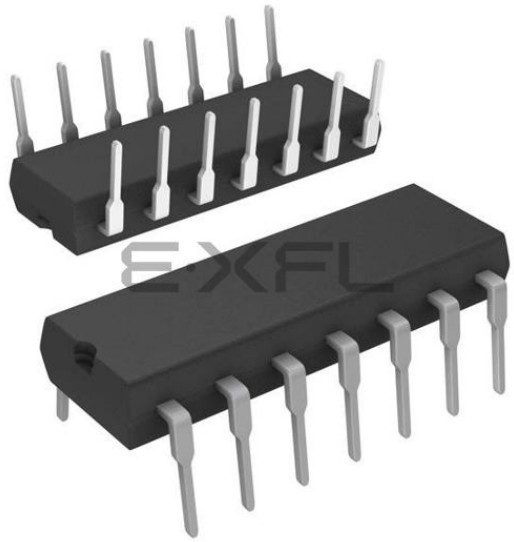

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Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	12
Program Memory Size	1.5KB (1K x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	72 x 8
Voltage - Supply (Vcc/Vdd)	2.5V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Through Hole
Package / Case	14-DIP (0.300", 7.62mm)
Supplier Device Package	14-PDIP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16lc505-04-p

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1.0 GENERAL DESCRIPTION

The PIC16C505 from Microchip Technology is a low-cost, high-performance, 8-bit, fully static, EPROM/ROM-based CMOS microcontroller. It employs a RISC architecture with only 33 single word/single cycle instructions. All instructions are single cycle (200 μs) except for program branches, which take two cycles. The PIC16C505 delivers performance an order of magnitude higher than its competitors in the same price category. The 12-bit wide instructions are highly symmetrical resulting in a typical 2:1 code compression over other 8-bit microcontrollers in its class. The easy to use and easy to remember instruction set reduces development time significantly.

The PIC16C505 product is equipped with special features that reduce system cost and power requirements. The Power-On Reset (POR) and Device Reset Timer (DRT) eliminate the need for external reset circuitry. There are five oscillator configurations to choose from, including INTRC internal oscillator mode and the power-saving LP (Low Power) oscillator mode. Power saving SLEEP mode, Watchdog Timer and code protection features improve system cost, power and reliability.

The PIC16C505 is available in the cost-effective One-Time-Programmable (OTP) version, which is suitable for production in any volume. The customer can take full advantage of Microchip's price leadership in OTP microcontrollers, while benefiting from the OTP's flexibility.

The PIC16C505 product is supported by a full-featured macro assembler, a software simulator, an in-circuit emulator, a 'C' compiler, a low-cost development programmer and a full featured programmer. All the tools are supported on IBM® PC and compatible machines.

1.1 Applications

The PIC16C505 fits in applications ranging from personal care appliances and security systems to low-power remote transmitters/receivers. The EPROM technology makes customizing application programs (transmitter codes, appliance settings, receiver frequencies, etc.) extremely fast and convenient. The small footprint packages, for through hole or surface mounting, make this microcontroller perfect for applications with space limitations. Low-cost, low-power, high-performance, ease of use and I/O flexibility make the PIC16C505 very versatile even in areas where no microcontroller use has been considered before (e.g., timer functions, replacement of "glue" logic and PLD's in larger systems, and coprocessor applications).

3.1 Clocking Scheme/Instruction Cycle

The clock input (OSC1/CLKIN pin) is internally divided by four to generate four non-overlapping quadrature clocks namely Q1, Q2, Q3 and Q4. Internally, the program counter is incremented every Q1, and the instruction is fetched from program memory and latched into the instruction register in Q4. It is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow is shown in Figure 3-2 and Example 3-1.

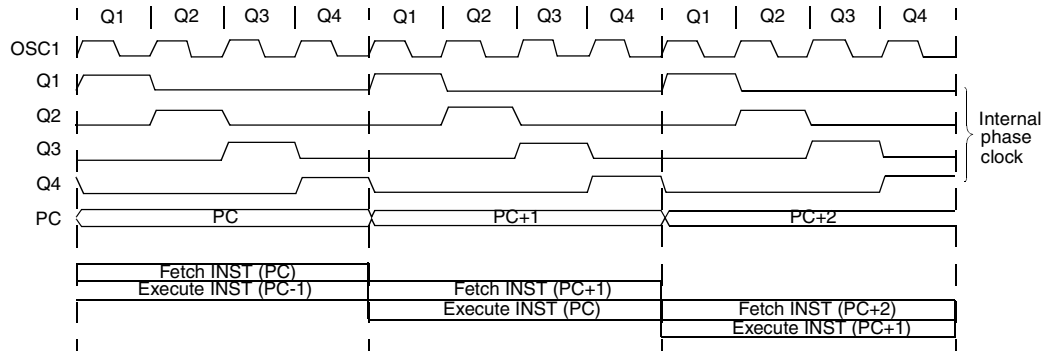
3.2 Instruction Flow/Pipelining

An Instruction cycle consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle, while decode and execute takes another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the program counter to change (e.g., `GOTO`) then two cycles are required to complete the instruction (Example 3-1).

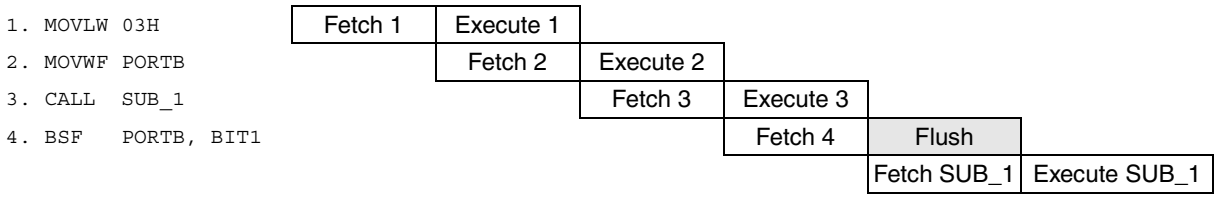
A fetch cycle begins with the program counter (PC) incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the Instruction Register (IR) in cycle Q1. This instruction is then decoded and executed during the Q2, Q3 and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).

FIGURE 3-2: CLOCK/INSTRUCTION CYCLE



EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW



All instructions are single cycle, except for any program branches. These take two cycles, since the fetch instruction is “flushed” from the pipeline, while the new instruction is being fetched and then executed.

FIGURE 6-2: TIMER0 TIMING: INTERNAL CLOCK/NO PRESCALE

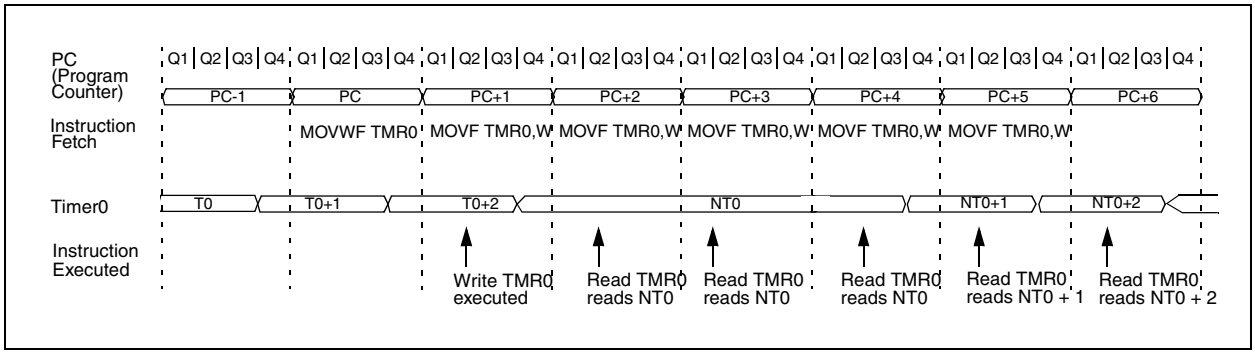


FIGURE 6-3: TIMER0 TIMING: INTERNAL CLOCK/PRESCALE 1:2

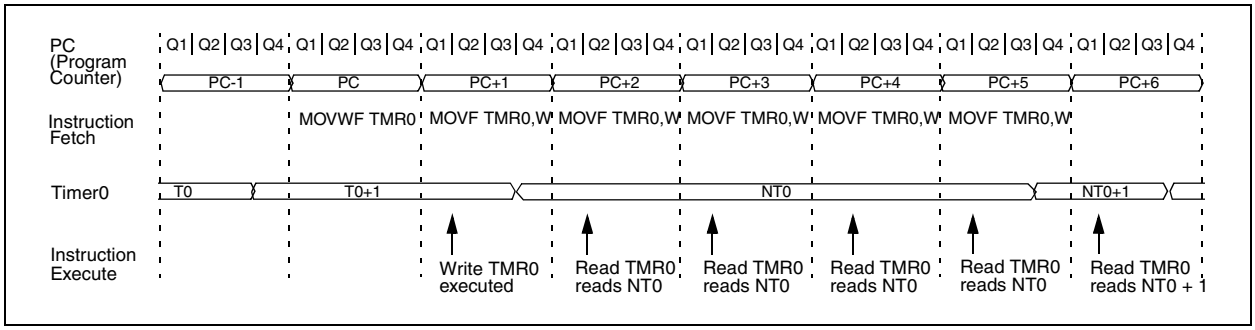


TABLE 6-1: REGISTERS ASSOCIATED WITH TIMER0

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-On Reset	Value on All Other Resets
01h	TMR0	Timer0 - 8-bit real-time clock/counter								xxxx xxxx	uuuu uuuu
N/A	OPTION	$\overline{\text{RBWU}}$	$\overline{\text{RBPU}}$	T0CS	T0SE	PSA	PS2	PS1	PS0	1111 1111	1111 1111
N/A	TRISC	—	—	RC5	RC4	RC3	RC2	RC1	RC0	--11 1111	--11 1111

Legend: Shaded cells not used by Timer0, - = unimplemented, x = unknown, u = unchanged.

6.2 Prescaler

An 8-bit counter is available as a prescaler for the Timer0 module or as a postscaler for the Watchdog Timer (WDT), respectively (Section 7.6). For simplicity, this counter is being referred to as “prescaler” throughout this data sheet. Note that the prescaler may be used by either the Timer0 module or the WDT, but not both. Thus, a prescaler assignment for the Timer0 module means that there is no prescaler for the WDT, and vice-versa.

The PSA and PS<2:0> bits (OPTION<3:0>) determine prescaler assignment and prescale ratio.

When assigned to the Timer0 module, all instructions writing to the TMR0 register (e.g., `CLRF 1`, `MOVWF 1`, `BSF 1,x`, etc.) will clear the prescaler. When assigned to WDT, a `CLRWDT` instruction will clear the prescaler along with the WDT. The prescaler is neither readable nor writable. On a RESET, the prescaler contains all '0's.

6.2.1 SWITCHING PRESCALER ASSIGNMENT

The prescaler assignment is fully under software control (i.e., it can be changed “on-the-fly” during program execution). To avoid an unintended device RESET, the following instruction sequence (Example 6-1) must be executed when changing the prescaler assignment from Timer0 to the WDT.

EXAMPLE 6-1: CHANGING PRESCALER (TIMER0→WDT)

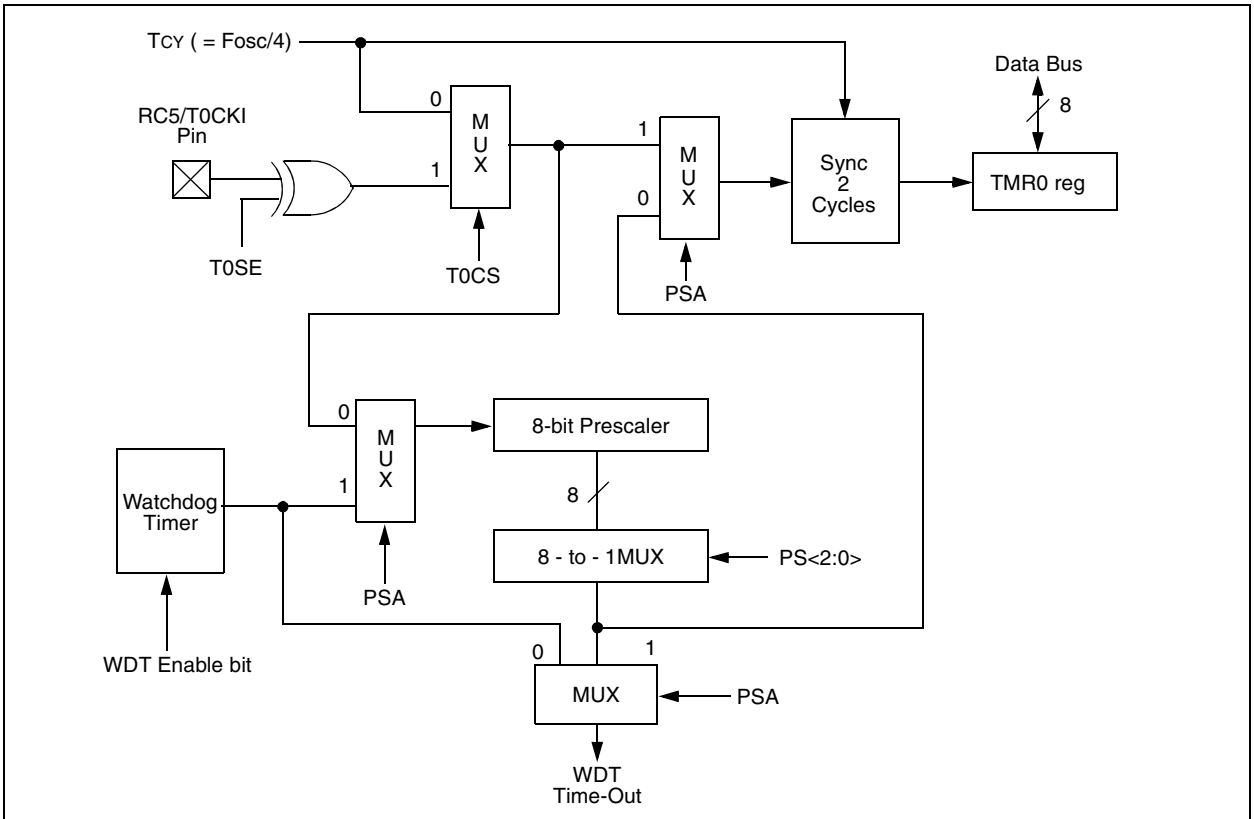
```
1.CLRWDT              ;Clear WDT
2.CLRF   TMR0         ;Clear TMR0 & Prescaler
3.MOVLW  '00xx1111'b  ;These 3 lines (5, 6, 7)
4.OPTION              ; are required only if
                      ; desired
5.CLRWDT              ;PS<2:0> are 000 or 001
6.MOVLW  '00xx1xxx'b  ;Set Postscaler to
7.OPTION              ; desired WDT rate
```

To change prescaler from the WDT to the Timer0 module, use the sequence shown in Example 6-2. This sequence must be used even if the WDT is disabled. A `CLRWDT` instruction should be executed before switching the prescaler.

EXAMPLE 6-2: CHANGING PRESCALER (WDT→TIMER0)

```
CLRWDT                ;Clear WDT and
                      ;prescaler
MOVLW   'xxxx0xxx'    ;Select TMR0, new
                      ;prescale value and
                      ;clock source
OPTION
```

FIGURE 6-5: BLOCK DIAGRAM OF THE TIMER0/WDT PRESCALER



Note: T0CS, T0SE, PSA, PS<2:0> are bits in the OPTION register.

7.2 Oscillator Configurations

7.2.1 OSCILLATOR TYPES

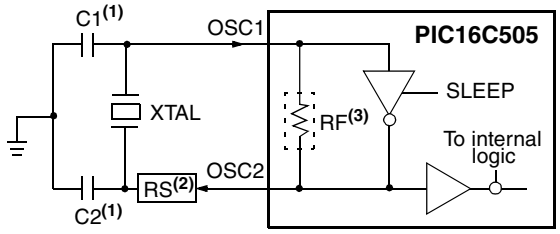
The PIC16C505 can be operated in four different oscillator modes. The user can program three configuration bits (FOSC<2:0>) to select one of these four modes:

- LP: Low Power Crystal
- XT: Crystal/Resonator
- HS: High Speed Crystal/Resonator
- INTRC: Internal 4 MHz Oscillator
- EXTRC: External Resistor/Capacitor

7.2.2 CRYSTAL OSCILLATOR / CERAMIC RESONATORS

In HS, XT or LP modes, a crystal or ceramic resonator is connected to the RB5/OSC1/CLKIN and RB4/OSC2/CLKOUT pins to establish oscillation (Figure 7-1). The PIC16C505 oscillator design requires the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in HS, XT or LP modes, the device can have an external clock source drive the RB5/OSC1/CLKIN pin (Figure 7-2).

FIGURE 7-1: CRYSTAL OPERATION (OR CERAMIC RESONATOR) (HS, XT OR LP OSC CONFIGURATION)



Note 1: See Capacitor Selection tables for recommended values of C1 and C2.
2: A series resistor (RS) may be required for AT strip cut crystals.
3: RF approx. value = 10 MΩ.

FIGURE 7-2: EXTERNAL CLOCK INPUT OPERATION (HS, XT OR LP OSC CONFIGURATION)

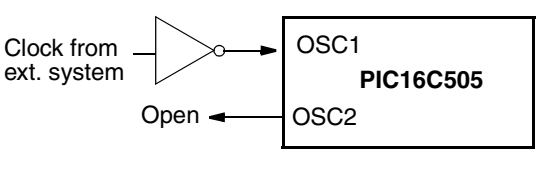


TABLE 7-1: CAPACITOR SELECTION FOR CERAMIC RESONATORS - PIC16C505

Osc Type	Resonator Freq	Cap. Range C1	Cap. Range C2
XT	4.0 MHz	30 pF	30 pF
HS	16 MHz	10-47 pF	10-47 pF

These values are for design guidance only. Since each resonator has its own characteristics, the user should consult the resonator manufacturer for appropriate values of external components.

TABLE 7-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATOR - PIC16C505

Osc Type	Resonator Freq	Cap.Range C1	Cap. Range C2
LP	32 kHz(1)	15 pF	15 pF
XT	200 kHz 1 MHz 4 MHz	47-68 pF 15 pF 15 pF	47-68 pF 15 pF 15 pF
HS	20 MHz	15-47 pF	15-47 pF

Note 1: For V_{DD} > 4.5V, C1 = C2 ≈ 30 pF is recommended.

These values are for design guidance only. Rs may be required to avoid overdriving crystals with low drive level specification. Since each crystal has its own characteristics, the user should consult the crystal manufacturer for appropriate values of external components.

7.2.3 EXTERNAL CRYSTAL OSCILLATOR CIRCUIT

Either a prepackaged oscillator or a simple oscillator circuit with TTL gates can be used as an external crystal oscillator circuit. Prepackaged oscillators provide a wide operating range and better stability. A well-designed crystal oscillator will provide good performance with TTL gates. Two types of crystal oscillator circuits can be used: one with parallel resonance, or one with series resonance.

Figure 7-3 shows implementation of a parallel resonant oscillator circuit. The circuit is designed to use the fundamental frequency of the crystal. The 74AS04 inverter performs the 180-degree phase shift that a parallel oscillator requires. The 4.7 kΩ resistor provides the negative feedback for stability. The 10 kΩ potentiometers bias the 74AS04 in the linear region. This circuit could be used for external oscillator designs.

FIGURE 7-3: EXTERNAL PARALLEL RESONANT CRYSTAL OSCILLATOR CIRCUIT

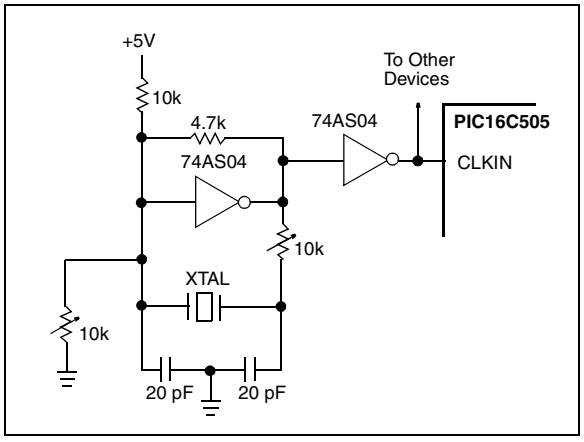
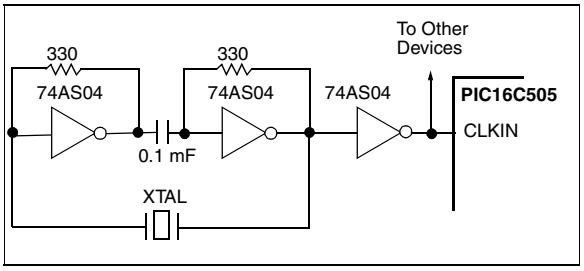


Figure 7-4 shows a series resonant oscillator circuit. This circuit is also designed to use the fundamental frequency of the crystal. The inverter performs a 180-degree phase shift in a series resonant oscillator circuit. The 330 Ω resistors provide the negative feedback to bias the inverters in their linear region.

FIGURE 7-4: EXTERNAL SERIES RESONANT CRYSTAL OSCILLATOR CIRCUIT



7.2.4 EXTERNAL RC OSCILLATOR

For timing insensitive applications, the RC device option offers additional cost savings. The RC oscillator frequency is a function of the supply voltage, the resistor (Rext) and capacitor (Cext) values, and the operating temperature. In addition to this, the oscillator frequency will vary from unit to unit due to normal process parameter variation. Furthermore, the difference in lead frame capacitance between package types will also affect the oscillation frequency, especially for low Cext values. The user also needs to take into account variation due to tolerance of external R and C components used.

Figure 7-5 shows how the R/C combination is connected to the PIC16C505. For Rext values below 2.2 kΩ, the oscillator operation may become unstable, or stop completely. For very high Rext values (e.g., 1 MΩ) the oscillator becomes sensitive to noise, humidity and leakage. Thus, we recommend keeping Rext between 3 kΩ and 100 kΩ.

Although the oscillator will operate with no external capacitor (Cext = 0 pF), we recommend using values above 20 pF for noise and stability reasons. With no or small external capacitance, the oscillation frequency can vary dramatically due to changes in external capacitances, such as PCB trace capacitance or package lead frame capacitance.

The Electrical Specifications section shows RC frequency variation from part to part due to normal process variation. The variation is larger for larger values of R (since leakage current variation will affect RC frequency more for large R) and for smaller values of C (since variation of input capacitance will affect RC frequency more).

Also, see the Electrical Specifications section for variation of oscillator frequency due to V_{DD} for given Rext/Cext values, as well as frequency variation due to operating temperature for given R, C and V_{DD} values.

FIGURE 7-5: EXTERNAL RC OSCILLATOR MODE

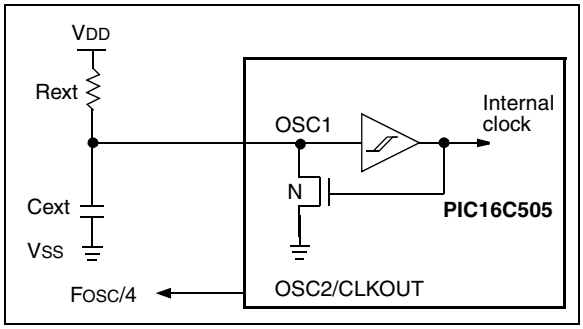
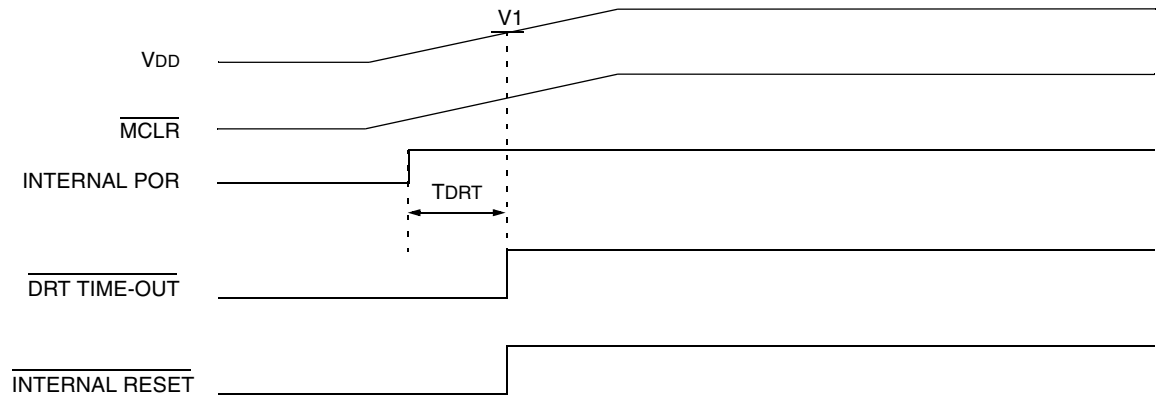


FIGURE 7-10: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): SLOW VDD RISE TIME



Note: When VDD rises slowly, the TDRT time-out expires long before VDD has reached its final value. In this example, the chip will reset properly if, and only if, V1 ≥ VDD min.

7.5 Device Reset Timer (DRT)

In the PIC16C505, the DRT runs any time the device is powered up. DRT runs from RESET and varies based on oscillator selection and reset type (see Table 7-5).

The DRT operates on an internal RC oscillator. The processor is kept in RESET as long as the DRT is active. The DRT delay allows VDD to rise above VDD min. and for the oscillator to stabilize.

Oscillator circuits based on crystals or ceramic resonators require a certain time after power-up to establish a stable oscillation. The on-chip DRT keeps the device in a RESET condition for approximately 18 ms after MCLR has reached a logic high (VIHMCLR) level. Thus, programming RB3/MCLR/VPP as MCLR and using an external RC network connected to the MCLR input is not required in most cases, allowing for savings in cost-sensitive and/or space restricted applications, as well as allowing the use of the RB3/MCLR/VPP pin as a general purpose input.

The Device Reset time delay will vary from chip to chip due to VDD, temperature and process variation. See AC parameters for details.

The DRT will also be triggered upon a Watchdog Timer time-out. This is particularly important for applications using the WDT to wake from SLEEP mode automatically.

Reset sources are POR, MCLR, WDT time-out and Wake-up on pin change. (See Section 7.9.2, Notes 1, 2, and 3, page 37.)

7.6 Watchdog Timer (WDT)

The Watchdog Timer (WDT) is a free running on-chip RC oscillator, which does not require any external components. This RC oscillator is separate from the external RC oscillator of the RB5/OSC1/CLKIN pin and the internal 4 MHz oscillator. That means that the WDT will run even if the main processor clock has been stopped, for example, by execution of a SLEEP instruction. During normal operation or SLEEP, a WDT reset or wake-up reset generates a device RESET.

The TO bit (STATUS<4>) will be cleared upon a Watchdog Timer reset.

The WDT can be permanently disabled by programming the configuration bit WDTE as a '0' (Section 7.1). Refer to the PIC16C505 Programming Specifications to determine how to access the configuration word.

TABLE 7-5: DRT (DEVICE RESET TIMER PERIOD)

Oscillator Configuration	POR Reset	Subsequent Resets
IntRC & ExtRC	18 ms (typical)	300 µs (typical)
HS, XT & LP	18 ms (typical)	18 ms (typical)

7.6.1 WDT PERIOD

The WDT has a nominal time-out period of 18 ms, (with no prescaler). If a longer time-out period is desired, a prescaler with a division ratio of up to 1:128 can be assigned to the WDT (under software control) by writing to the OPTION register. Thus, a time-out period of a nominal 2.3 seconds can be realized. These periods vary with temperature, VDD and part-to-part process variations (see DC specs).

Under worst case conditions (VDD = Min., Temperature = Max., max. WDT prescaler), it may take several seconds before a WDT time-out occurs.

7.6.2 WDT PROGRAMMING CONSIDERATIONS

The CLRWDT instruction clears the WDT and the postscaler, if assigned to the WDT, and prevents it from timing out and generating a device RESET.

The SLEEP instruction resets the WDT and the postscaler, if assigned to the WDT. This gives the maximum SLEEP time before a WDT wake-up reset.

FIGURE 7-11: WATCHDOG TIMER BLOCK DIAGRAM

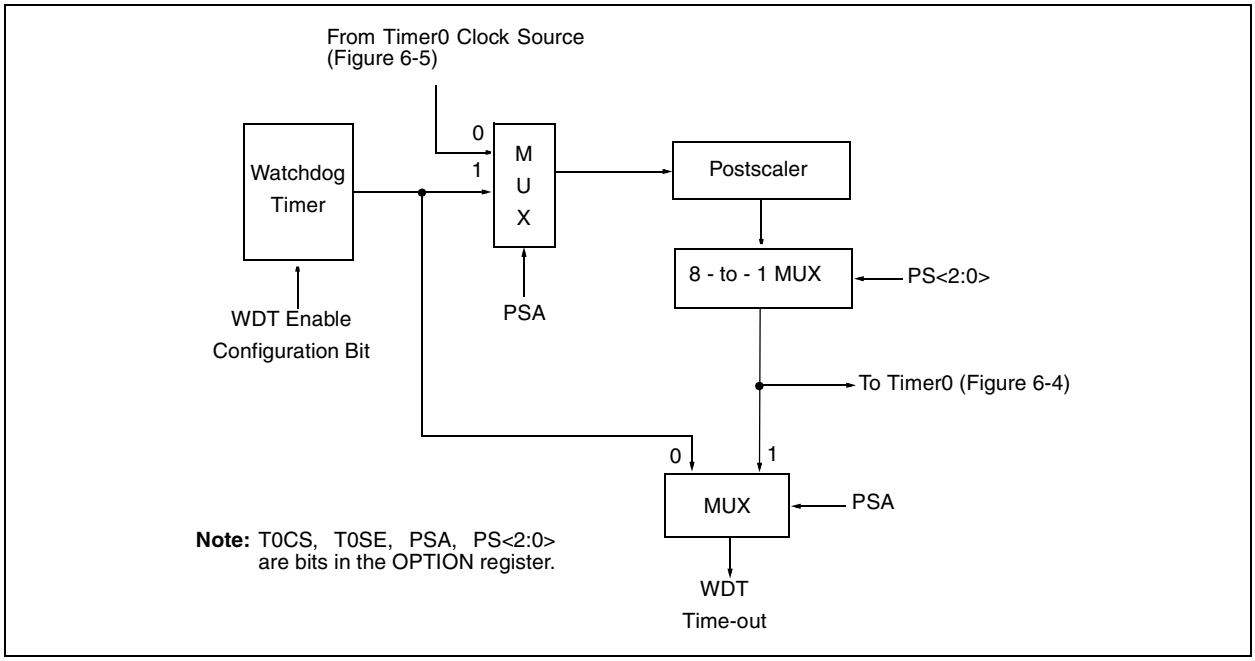


TABLE 7-6: SUMMARY OF REGISTERS ASSOCIATED WITH THE WATCHDOG TIMER

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-On Reset	Value on All Other Resets
N/A	OPTION	$\overline{RBWU}$	$\overline{RBPU}$	T0CS	T0SE	PSA	PS2	PS1	PS0	1111 1111	1111 1111

Legend: Shaded boxes = Not used by Watchdog Timer, — = unimplemented, read as '0', u = unchanged.

TABLE 8-2: INSTRUCTION SET SUMMARY

Mnemonic, Operands		Description	Cycles	12-Bit Opcode MSb	LSb	Status Affected	Notes
ADDWF	**f,d**	Add W and f	1	0001 11df ffff		C,DC,Z	1,2,4
ANDWF	**f,d**	AND W with f	1	0001 01df ffff		Z	2,4
CLRF	**f**	Clear f	1	0000 011f ffff		Z	4
CLRW	**–**	Clear W	1	0000 0100 0000		Z	
COMF	**f, d**	Complement f	1	0010 01df ffff		Z	
DECF	**f, d**	Decrement f	1	0000 11df ffff		Z	2,4
DECFSZ	**f, d**	Decrement f, Skip if 0	1(2)	0010 11df ffff		None	2,4
INCF	**f, d**	Increment f	1	0010 10df ffff		Z	2,4
INCFSZ	**f, d**	Increment f, Skip if 0	1(2)	0011 11df ffff		None	2,4
IORWF	**f, d**	Inclusive OR W with f	1	0001 00df ffff		Z	2,4
MOVF	**f, d**	Move f	1	0010 00df ffff		Z	2,4
MOVWF	**f**	Move W to f	1	0000 001f ffff		None	1,4
NOP	**–**	No Operation	1	0000 0000 0000		None	
RLF	**f, d**	Rotate left f through Carry	1	0011 01df ffff		C	2,4
RRF	**f, d**	Rotate right f through Carry	1	0011 00df ffff		C	2,4
SUBWF	**f, d**	Subtract W from f	1	0000 10df ffff		C,DC,Z	1,2,4
SWAPF	**f, d**	Swap f	1	0011 10df ffff		None	2,4
XORWF	**f, d**	Exclusive OR W with f	1	0001 10df ffff		Z	2,4
BIT-ORIENTED FILE REGISTER OPERATIONS							
BCF	**f, b**	Bit Clear f	1	0100 bbbf ffff		None	2,4
BSF	**f, b**	Bit Set f	1	0101 bbbf ffff		None	2,4
BTFSC	**f, b**	Bit Test f, Skip if Clear	1 (2)	0110 bbbf ffff		None	
BTFSS	**f, b**	Bit Test f, Skip if Set	1 (2)	0111 bbbf ffff		None	
LITERAL AND CONTROL OPERATIONS							
ANDLW	**k**	AND literal with W	1	1110 kkkk kkkk		Z	
CALL	**k**	Call subroutine	2	1001 kkkk kkkk		None	1
CLRWDT	**k**	Clear Watchdog Timer	1	0000 0000 0100		$\overline{TO}$, $\overline{PD}$	
GOTO	**k**	Unconditional branch	2	101k kkkk kkkk		None	
IORLW	**k**	Inclusive OR Literal with W	1	1101 kkkk kkkk		Z	
MOVLW	**k**	Move Literal to W	1	1100 kkkk kkkk		None	
OPTION	**–**	Load OPTION register	1	0000 0000 0010		None	
RETLW	**k**	Return, place Literal in W	2	1000 kkkk kkkk		None	
SLEEP	**–**	Go into standby mode	1	0000 0000 0011		$\overline{TO}$, $\overline{PD}$	
TRIS	**f**	Load TRIS register	1	0000 0000 0fff		None	3
XORLW	**k**	Exclusive OR Literal to W	1	1111 kkkk kkkk		Z	

Note 1: The 9th bit of the program counter will be forced to a '0' by any instruction that writes to the PC except for GOTO. (Section 4.6)

2: When an I/O register is modified as a function of itself (e.g. MOVF PORTB, 1), the value used will be that value present on the pins themselves. For example, if the data latch is '1' for a pin configured as input and is driven low by an external device, the data will be written back with a '0'.

3: The instruction TRIS f, where f = 6 causes the contents of the W register to be written to the tristate latches of PORTB. A '1' forces the pin to a hi-impedance state and disables the output buffers.

4: If this instruction is executed on the TMR0 register (and, where applicable, d = 1), the prescaler will be cleared (if assigned to TMR0).

ADDWF **Add W and f**

Syntax: [*label*] ADDWF f,d

Operands: $0 \le f \le 31$
$d \in [0,1]$

Operation: (W) + (f) → (dest)

Status Affected: C, DC, Z

Encoding:

0001	11df	ffff

Description: Add the contents of the W register and register 'f'. If 'd' is 0, the result is stored in the W register. If 'd' is '1', the result is stored back in register 'f'.

Words: 1

Cycles: 1

Example:
```
ADDWF   FSR, 0
```
Before Instruction
W = 0x17
FSR = 0xC2

After Instruction
W = 0xD9
FSR = 0xC2

ANDLW **And literal with W**

Syntax: [*label*] ANDLW k

Operands: $0 \le k \le 255$

Operation: (W).AND. (k) → (W)

Status Affected: Z

Encoding:

1110	kkkk	kkkk

Description: The contents of the W register are AND'ed with the eight-bit literal 'k'. The result is placed in the W register.

Words: 1

Cycles: 1

Example:
```
ANDLW   0x5F
```
Before Instruction
W = 0xA3

After Instruction
W = 0x03

ANDWF **AND W with f**

Syntax: [*label*] ANDWF f,d

Operands: $0 \le f \le 31$
$d \in [0,1]$

Operation: (W) .AND. (f) → (dest)

Status Affected: Z

Encoding:

0001	01df	ffff

Description: The contents of the W register are AND'ed with register 'f'. If 'd' is 0, the result is stored in the W register. If 'd' is '1', the result is stored back in register 'f'.

Words: 1

Cycles: 1

Example:
```
ANDWF   FSR,    1
```
Before Instruction
W = 0x17
FSR = 0xC2

After Instruction
W = 0x17
FSR = 0x02

BCF **Bit Clear f**

Syntax: [*label*] BCF f,b

Operands: $0 \le f \le 31$
$0 \le b \le 7$

Operation: 0 → (f<b>)

Status Affected: None

Encoding:

0100	bbbf	ffff

Description: Bit 'b' in register 'f' is cleared.

Words: 1

Cycles: 1

Example:
```
BCF     FLAG_REG,  7
```
Before Instruction
FLAG_REG = 0xC7

After Instruction
FLAG_REG = 0x47

10.0 ELECTRICAL CHARACTERISTICS - PIC16C505

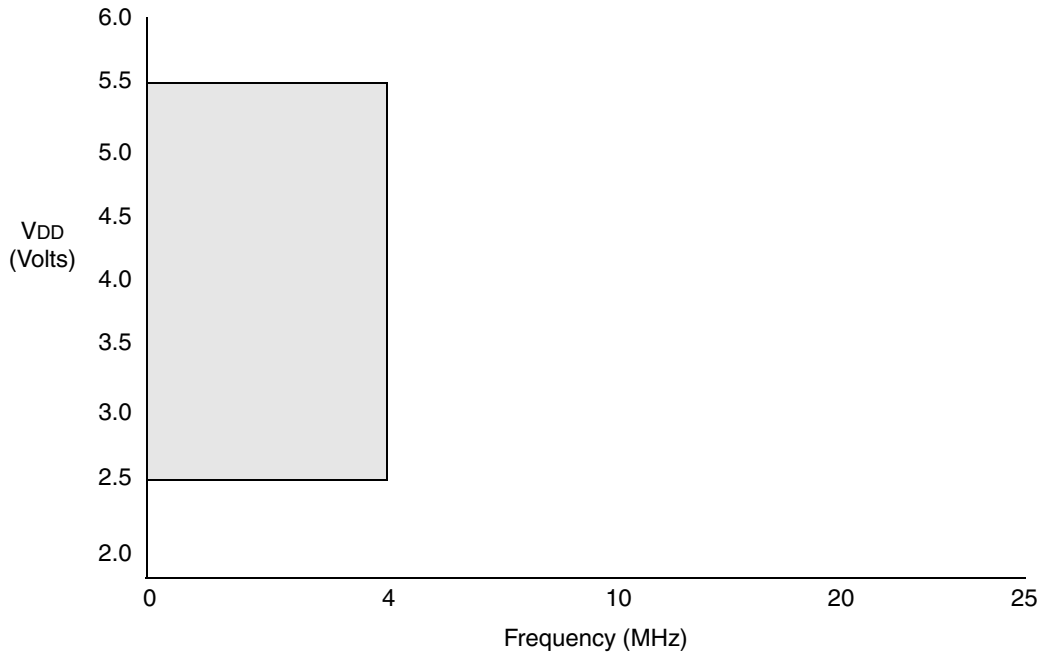
Absolute Maximum Ratings†

Ambient Temperature under bias ..... –40°C to +125°C
Storage Temperature ..... –65°C to +150°C
Voltage on V_{DD} with respect to V_{SS} ..... 0 to +7 V
Voltage on $\overline{MCLR}$ with respect to V_{SS} ..... 0 to +14 V
Voltage on all other pins with respect to V_{SS} ..... –0.6 V to (V_{DD} + 0.6 V)
Total Power Dissipation(1) ..... 700 mW
Max. Current out of V_{SS} pin ..... 150 mA
Max. Current into V_{DD} pin ..... 125 mA
Input Clamp Current, I_{IK} (V_I < 0 or V_I > V_{DD}) ..... ±20 mA
Output Clamp Current, I_{OK} (V_O < 0 or V_O > V_{DD}) ..... ±20 mA
Max. Output Current sunk by any I/O pin ..... 25 mA
Max. Output Current sourced by any I/O pin ..... 25 mA
Max. Output Current sourced by I/O port ..... 100 mA
Max. Output Current sunk by I/O port ..... 100 mA

Note 1: Power Dissipation is calculated as follows: $P_{DIS} = V_{DD} \times \{I_{DD} - \sum I_{OH}\} + \sum \{(V_{DD}-V_{OH}) \times I_{OH}\} + \sum(V_{OL} \times I_{OL})$

†NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

FIGURE 10-3: PIC16LC505 VOLTAGE-FREQUENCY GRAPH, -40°C ≤ TA ≤ +85°C



Note 1: The shaded region indicates the permissible combinations of voltage and frequency.

2: The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.

10.1 DC CHARACTERISTICS: PIC16C505-04 (Commercial, Industrial, Extended) PIC16C505-20(Commercial, Industrial, Extended)

DC Characteristics Power Supply Pins			Standard Operating Conditions (unless otherwise specified) Operating Temperature 0°C ≤ TA ≤ +70°C (commercial) –40°C ≤ TA ≤ +85°C (industrial) –40°C ≤ TA ≤ +125°C (extended)				
Parm. No.	**Characteristic**	**Sym**	**Min**	**Typ(1)**	**Max**	**Units**	**Conditions**
D001	Supply Voltage	VDD	3.0		5.5	V	See Figure 10-1 through Figure 10-3
D002	RAM Data Retention Voltage(2)	VDR	—	1.5*	—	V	Device in SLEEP mode
D003	VDD Start Voltage to ensure Power-on Reset	VPOR	—	VSS	—	V	See section on Power-on Reset for details
D004	VDD Rise Rate to ensure Power-on Reset	SVDD	0.05*	—	—	V/ms	See section on Power-on Reset for details
D010	Supply Current(3)	IDD	— — — — — —	0.8 0.6 3 4 4.5 19	1.4 1.0 7 12 16 27	mA mA mA mA mA µA	FOSC = 4MHz, VDD = 5.5V, WDT disabled (Note 4)* FOSC = 4MHz, VDD = 3.0V, WDT disabled (Note 4) FOSC = 10MHz, VDD = 3.0V, WDT disabled (Note 6) FOSC = 20MHz, VDD = 4.5V, WDT disabled FOSC = 20MHz, VDD = 5.5V, WDT disabled* FOSC = 32kHz, VDD = 3.0V, WDT disabled (Note 6)
D020	Power-Down Current (5)	IPD	— — — —	0.25 0.4 3 5	4 5.5 8 14	µA µA µA µA	VDD = 3.0V (Note 6) VDD = 4.5V* (Note 6) VDD = 5.5V, Industrial VDD = 5.5V, Extended Temp.
D022	WDT Current(5)	ΔIWDT	—	2.2	5	µA	VDD = 3.0V (Note 6)
1A	LP Oscillator Operating Frequency RC Oscillator Operating Frequency XT Oscillator Operating Frequency HS Oscillator Operating Frequency	Fosc	0 0 0 0	— — — —	200 4 4 20	kHz MHz MHz MHz	All temperatures All temperatures All temperatures All temperatures

* These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

2: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

3: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, $\overline{MCLR}$ = VDD; WDT enabled/disabled as specified.

b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode.

4: Does not include current through Rext. The current through the resistor can be estimated by the formula: IR = VDD/2Rext (mA) with Rext in kOhm.

5: The power down current in SLEEP mode does not depend on the oscillator type. Power down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD or VSS.

6: Commercial temperature range only.

10.2 DC CHARACTERISTICS: PIC16LC505-04 (Commercial, Industrial)

DC Characteristics Power Supply Pins			Standard Operating Conditions (unless otherwise specified) Operating Temperature 0°C ≤ TA ≤ +70°C (commercial) –40°C ≤ TA ≤ +85°C (industrial)				
Parm. No.	**Characteristic**	**Sym**	**Min**	**Typ(1)**	**Max**	**Units**	**Conditions**
D001	Supply Voltage	VDD	2.5	—	5.5	V	See Figure 10-1 through Figure 10-3
D002	RAM Data Retention Voltage(2)	VDR	—	1.5*	—	V	Device in SLEEP mode
D003	VDD Start Voltage to ensure Power-on Reset	VPOR	—	VSS	—	V	See section on Power-on Reset for details
D004	VDD Rise Rate to ensure Power-on Reset	SVDD	0.05*	—	—	V/ms	See section on Power-on Reset for details
D010	Supply Current(3)	IDD	—	0.8	1.4	mA	FOSC = 4MHz, VDD = 5.5V, WDT disabled (Note 4)*
			—	0.4	0.8	mA	FOSC = 4MHz, VDD = 2.5V, WDT disabled (Note 4)
			—	15	23	µA	FOSC = 32kHz, VDD = 2.5V, WDT disabled (Note 6)
D020	Power-Down Current (5)	IPD	—	0.25	3	µA	VDD = 2.5V (Note 6)
			—	0.25	4	µA	VDD = 3.0V * (Note 6)
			—	3	8	µA	VDD = 5.5V Industrial
D022	WDT Current(5)	ΔIWDT	—	2.0	4	µA	VDD = 2.5V (Note 6)
1A	LP Oscillator Operating Frequency	FOSC	0	—	200	kHz	All temperatures
	RC Oscillator Operating Frequency		0	—	4	MHz	All temperatures
	XT Oscillator Operating Frequency		0	—	4	MHz	All temperatures
	HS Oscillator Operating Frequency		0	—	4	MHz	All temperatures

* These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

2: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

3: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, $\overline{MCLR}$ = VDD; WDT enabled/disabled as specified.

b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode.

4: Does not include current through Rext. The current through the resistor can be estimated by the formula: IR = VDD/2Rext (mA) with Rext in kOhm.

5: The power down current in SLEEP mode does not depend on the oscillator type. Power down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD or VSS.

6: Commercial temperature range only.

10.5 Timing Diagrams and Specifications

FIGURE 10-5: EXTERNAL CLOCK TIMING - PIC16C505

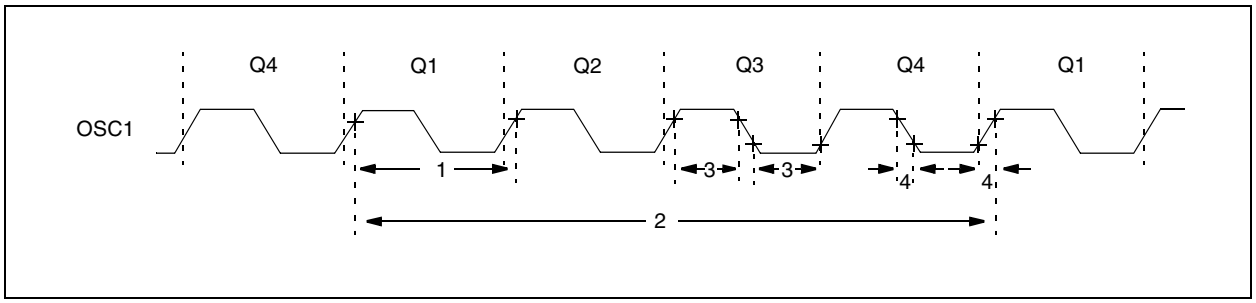


TABLE 10-2: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C505

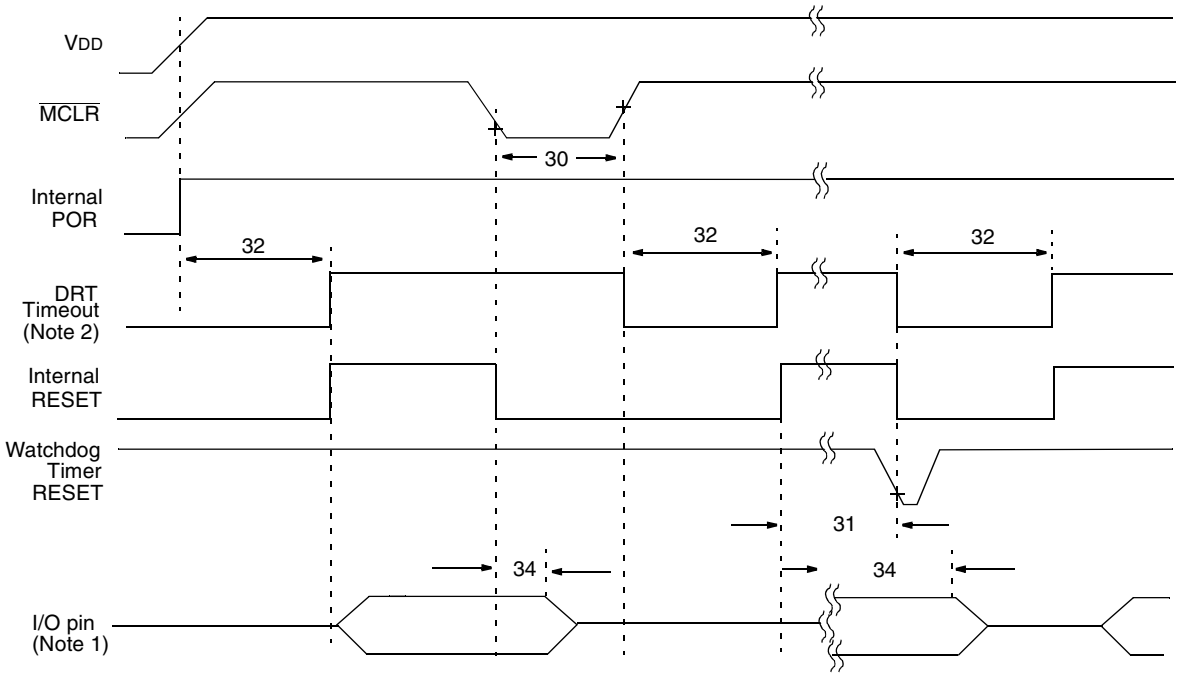
AC Characteristics	Standard Operating Conditions (unless otherwise specified) Operating Temperature 0°C ≤ TA ≤ +70°C (commercial), –40°C ≤ TA ≤ +85°C (industrial), –40°C ≤ TA ≤ +125°C (extended) Operating Voltage VDD range is described in Section 10.1						
Parameter No.	**Sym**	**Characteristic**	**Min**	**Typ(1)**	**Max**	**Units**	**Conditions**
1A	FOSC	External CLKIN Frequency(2)	DC	—	4	MHz	XT osc mode
			DC	—	4	MHz	HS osc mode (PIC16C505-04)
			DC	—	20	MHz	HS osc mode (PIC16C505-20)
			DC	—	200	kHz	LP osc mode
		Oscillator Frequency(2)	DC	—	4	MHz	EXTRC osc mode
			0.1	—	4	MHz	XT osc mode
			4	—	4	MHz	HS osc mode (PIC16C505-04)
			DC	—	200	kHz	LP osc mode
1	TOSC	External CLKIN Period(2)	250	—	—	ns	XT osc mode
			50	—	—	ns	HS osc mode (PIC16C505-20)
				—	—	µs	LP osc mode
		Oscillator Period(2)	250	—	—	ns	EXTRC osc mode
			250	—	10,000	ns	XT osc mode
			250	—	250	ns	HS ocs mode (PIC16C505-04)
			50	—	250	ns	HS ocs mode (PIC16C505-20)
			5	—	—	µs	LP osc mode
2	TCY	Instruction Cycle Time	—	4/FOSC	DC	ns	
			200	—		ns	

* These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

2: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.
When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

FIGURE 10-7: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C505



Note 1: I/O pins must be taken out of hi-impedance mode by enabling the output drivers in software.

2: Runs in $\overline{MCLR}$ or WDT reset only in XT, LP and HS modes.

TABLE 10-5: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C505

AC Characteristics	**Standard Operating Conditions (unless otherwise specified)** Operating Temperature 0°C ≤ TA ≤ +70°C (commercial) –40°C ≤ TA ≤ +85°C (industrial) –40°C ≤ TA ≤ +125°C (extended) Operating Voltage VDD range is described in Section 10.1						
Parameter No.	**Sym**	**Characteristic**	**Min**	**Typ(1)**	**Max**	**Units**	**Conditions**
30	TmcL	$\overline{MCLR}$ Pulse Width (low)	2000*	—	—	ns	VDD = 5.0 V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9*	18*	30*	ms	VDD = 5.0 V (Commercial)
32	TDRT	Device Reset Timer Period(2)	9*	18*	30*	ms	VDD = 5.0 V (Commercial)
34	Tioz	I/O Hi-impedance from $\overline{MCLR}$ Low	—	—	2000*	ns	

* These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

TABLE 10-6: DRT (DEVICE RESET TIMER PERIOD - PIC16C505

Oscillator Configuration	**POR Reset**	**Subsequent Resets**
IntRC & ExtRC	18 ms (typical)	300 µs (typical)
XT, HS & LP	18 ms (typical)	18 ms (typical)

FIGURE 10-8: TIMER0 CLOCK TIMINGS - PIC16C505

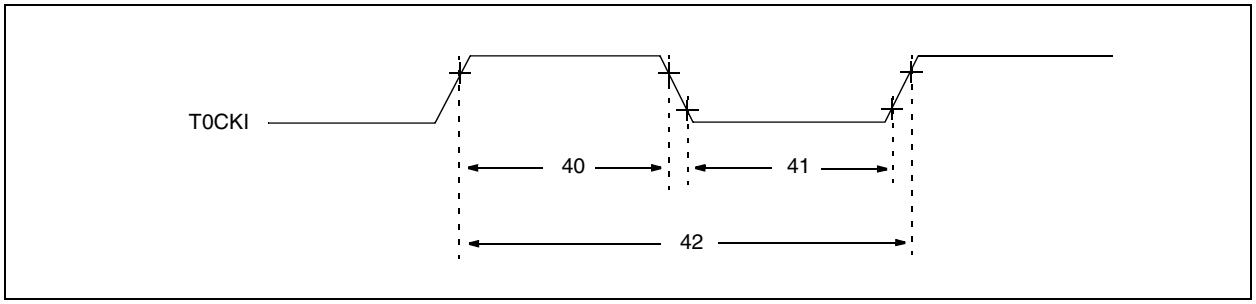


TABLE 10-7: TIMER0 CLOCK REQUIREMENTS - PIC16C505

AC Characteristics				Standard Operating Conditions (unless otherwise specified) Operating Temperature 0°C ≤ TA ≤ +70°C (commercial) –40°C ≤ TA ≤ +85°C (industrial) –40°C ≤ TA ≤ +125°C (extended) Operating Voltage VDD range is described in Section 10.1.				
Parm No.	**Sym**	**Characteristic**		**Min**	**Typ(1)**	**Max**	**Units**	**Conditions**
40	Tt0H	T0CKI High Pulse Width	No Prescaler	0.5 TCY + 20*	—	—	ns	
			With Prescaler	10*	—	—	ns	
41	Tt0L	T0CKI Low Pulse Width	No Prescaler	0.5 TCY + 20*	—	—	ns	
			With Prescaler	10*	—	—	ns	
42	Tt0P	T0CKI Period		20 or TCY + 40* N	—	—	ns	Whichever is greater. N = Prescale Value (1, 2, 4,..., 256)

* These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

11.0 DC AND AC CHARACTERISTICS - PIC16C505

The graphs and tables provided in this section are for design guidance and are not tested. In some graphs or tables the data presented are outside specified operating range (e.g., outside specified VDD range). This is for information only and devices will operate properly only within the specified range.

The data presented in this section is a statistical summary of data collected on units from different lots over a period of time. “Typical” represents the mean of the distribution while “max” or “min” represents (mean + 3σ) and (mean – 3σ) respectively, where σ is standard deviation.

FIGURE 11-1: CALIBRATED INTERNAL RC FREQUENCY RANGE VS. TEMPERATURE (VDD = 5.0V) (INTERNAL RC IS CALIBRATED TO 25°C, 5.0V)

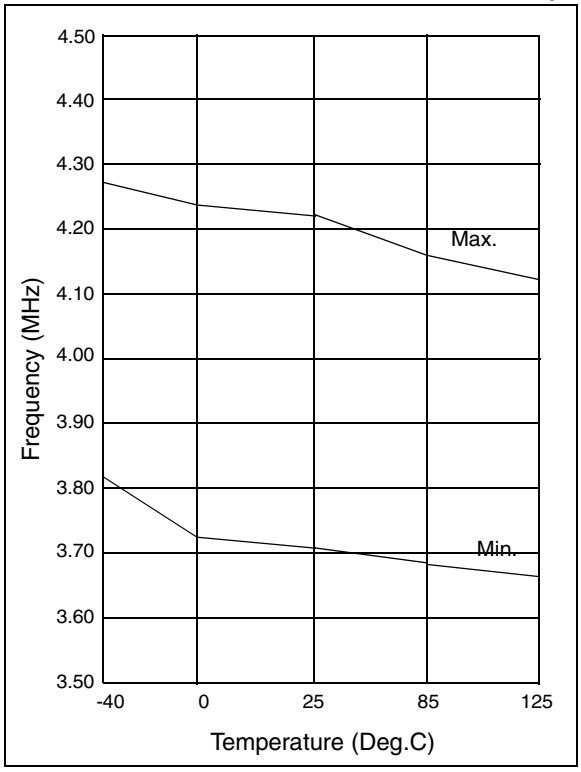
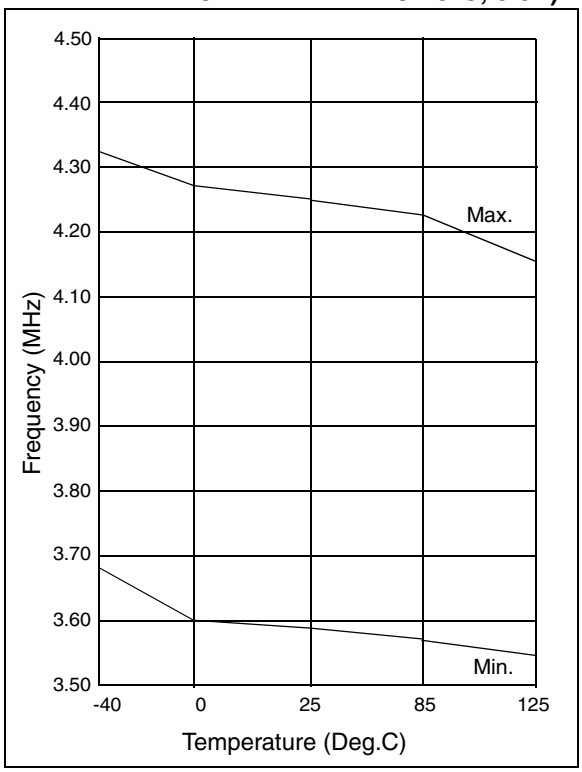
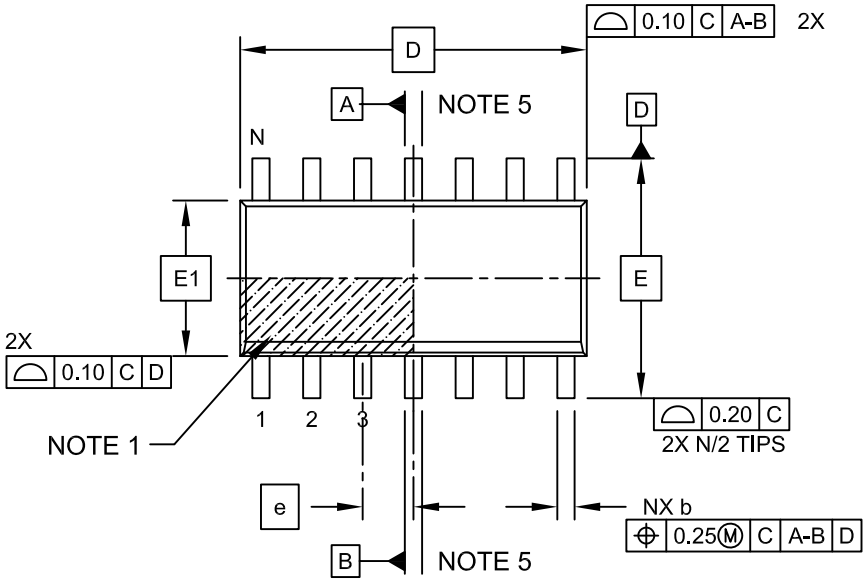


FIGURE 11-2: CALIBRATED INTERNAL RC FREQUENCY RANGE VS. TEMPERATURE (VDD = 2.5V) (INTERNAL RC IS CALIBRATED TO 25°C, 5.0V)

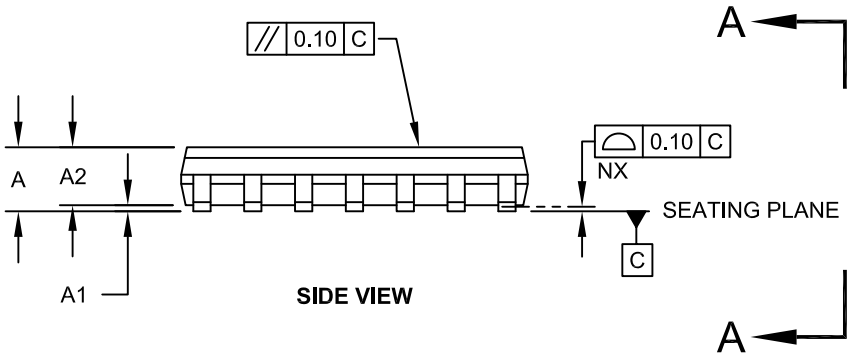


14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

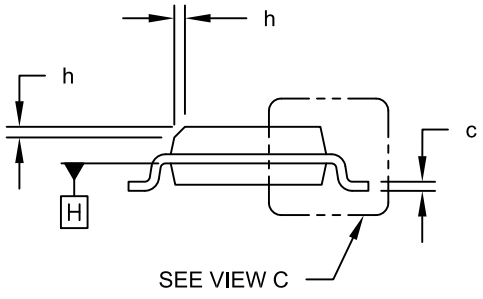
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



TOP VIEW



SIDE VIEW



VIEW A-A

Microchip Technology Drawing No. C04-065C Sheet 1 of 2